VS-6F(R) Series

Vishay Semiconductors



Standard Recovery Diodes (Stud Version), 6 A



- High surge current capability
- Avalanche types available
- Stud cathode and stud anode version
- Wide current range
- Types up to 1200 V V_{RRM}
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- Battery charges

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
		6	А	
I _{F(AV)}	T _C	160	°C	
I _{F(RMS)}		9.5	А	
I _{FSM}	50 Hz	159	٨	
	60 Hz	167	A	
l ² t	50 Hz	134	A ² s	
	60 Hz	141	A-s	
V _{RRM}	Range	100 to 1200	V	
TJ		-65 to 175	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	V _{R(BR)} , MINIMUM AVALANCHE VOLTAGE V ⁽¹⁾	I _{RRM} MAXIMUM AT T _J = 175 °C mA
	10	100	150	-	
	20	200	275	-	
	40	400	500	500	
VS-6F(R)	60	600	725	750	12
	80	800	950	950	
	100	1000	1200	1150	
	120	1200	1400	1350	

Note

 $^{(1)}\,$ Avalanche version only available from V_{RRM} 400 V to 1200 V

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PRODUCT SUMMARY			
I _{F(AV)}	6 A		
Package	DO-203AA (DO-4)		
Circuit configuration	Single diode		

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FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current		180° conduction, half sine wave			6	А
at case temperature	I _{F(AV)}	180 conduction, than sine wave		160	°C	
Maximum RMS forward current	I _{F(RMS)}			9.5	А	
Maximum non-repetitive peak reverse power PF		10 μ s square pulse, T _J = T _J maximum		4	K/W	
	I _{FSM}	t = 10 ms	No voltage	Sinusoidal half wave,	159	A
Maximum peak, one cycle forward,		t = 8.3 ms	reapplied		167	
non-repetitive surge current		t = 10 ms	100 % V _{RRM} reapplied		134	
		t = 8.3 ms			141	
		t = 10 ms	No voltage	initial T _J = T _J maximum	127	A ² s
Maximum 12t fau fusia a	l ² t	t = 8.3 ms	reapplied		116	
Maximum I ² t for fusing		t = 10 ms	100 % V _{BBM}		90	
		t = 8.3 ms	reapplied		82	
Maximum I ² √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied		1270	A²√s	
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $T_J = T_J$ maximum			0.63	v
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi x I_{F(AV)}), T_J = T_J maximum$		0.86		
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		15.7		
High level value of forward slope resistance r _{f2}		$(I > \pi \times I_{F(AV)}), T_J = T_J maximum$		5.6	mΩ	
Maximum forward voltage drop		$I_{pk} = 19 \text{ A}, T_J = 25 \text{ °C}, t_p = 400 \mu\text{s}$ rectangular wave		1.10	V	

Note

⁽¹⁾ Available only for avalanche version, all other parameters the same as 6F

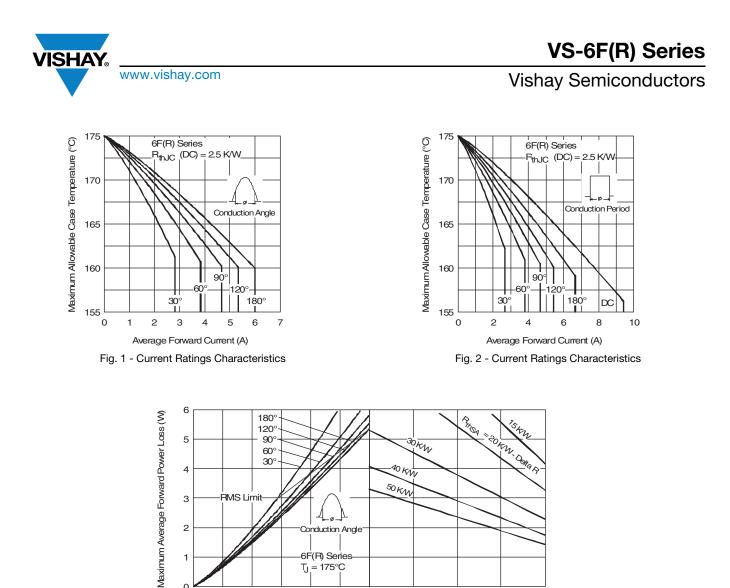
THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		UNITS	
Maximum junction temperature range	TJ		-65 to 175	*0	
Maximum storage temperature range	T _{Stg}		-65 to 200	C °C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	К/W	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.5		
Mounting torque, ± 10 %		Lubricated threads (Not lubricated threads)	1.2 (1.5)	N ⋅ m (lbf ⋅ in)	
Approvimate weight			7	g	
Approximate weight			0.25	OZ.	
Case style		See dimensions - link at the end of datasheet	DO-203A	A (DO-4)	

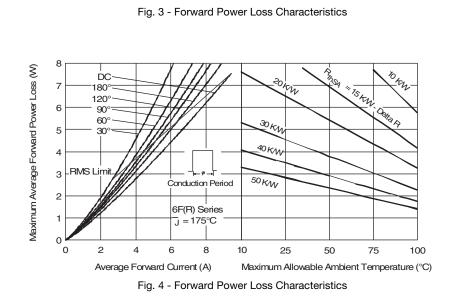
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.34	0.29			
120°	0.44	0.48			
90°	0.57	0.63	$T_J = T_J$ maximum	K/W	
60°	0.85	0.88			
30°	1.37	1.39			

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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6

5

25

50

Maximum Allowable Ambient Temperature (°C)

75

100

0

0

1

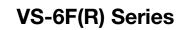
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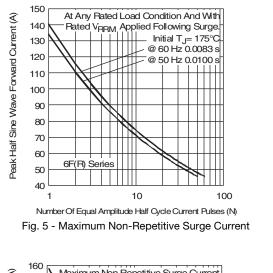
Average Forward Current (A)

4





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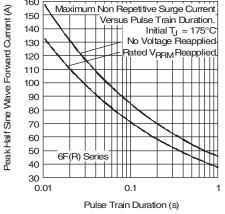
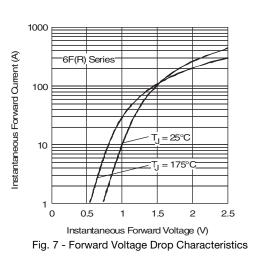


Fig. 6 - Maximum Non-Repetitive Surge Current





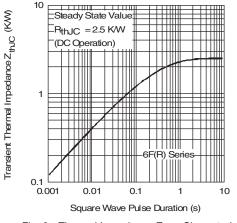
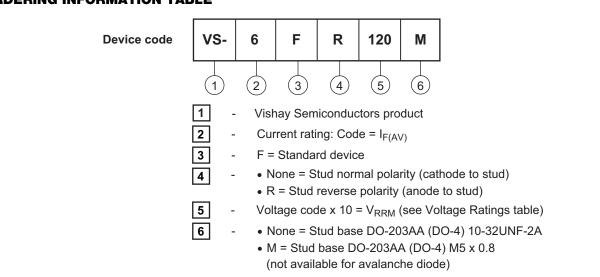


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



LINKS TO RELATED DOCUMENTS			
Dimensions www.vishay.com/doc?95311			
Revision: 28-Jan-14	4 Document Number: 93519		
For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com			

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R 0.40 R (0.02)

Ø 6.8 (0.27)

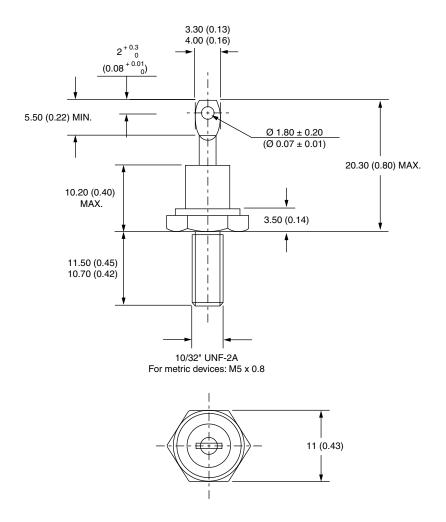
 0.8 ± 0.1

 (0.03 ± 0.004)



DO-203AA (DO-4)

DIMENSIONS in millimeters (inches)







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